NSN 5961-00-039-8814

Transistor - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

Between 0.560 inches and 0.650 inches

Overall Height:

0.190 inches

Overall Width:

Between 0.380 inches and 0.420 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 7.0 breakdown voltage, emitter-to-base, collector open and 75.0 breakdown

voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

4.00 amperes source cutoff current and 2.00 amperes source cutoff current

Power Rating Per Characteristic:

36.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 pin

Specification Data:

80131-release5736 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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